

64K (8K x 8) Low-Voltage CMOS EPROM

FEATURES

- Wide voltage range 3.0V to 5.5V
- High speed performance
 - 200 ns access time available at 3.0V
- CMOS Technology for low power consumption
 - 8 mA active current at 3.0V
 - 20 mA active current at 5.5V
 - 100 μ A standby current
- Factory programming available
- Auto-insertion-compatible plastic packages
- Auto ID aids automated programming
- Separate chip enable and output enable controls
- High speed "express" programming algorithm
- Organized 8K x 8: JEDEC standard pinouts
 - 28-pin Dual-in-line package
 - 32-pin PLCC Package
 - 28-pin SOIC package
 - Tape and reel
- Available for the following temperature ranges:
 - Commercial: 0°C to +70°C
 - Industrial: -40°C to +85°C

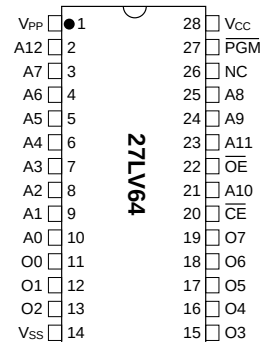
DESCRIPTION

The Microchip Technology Inc. 27LV64 is a low-voltage (3.0 volt) CMOS EPROM designed for battery powered applications. The device is organized as 8K x 8 (8K-Byte) non-volatile memory product. The 27LV64 consumes only 8mA maximum of active current during a 3.0 volt read operation therefore improving battery performance. This device is designed for very low voltage applications where conventional 5.0 volt only EPROMs can not be used. Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 200 ns at 3.0V. This device allows system designers the ability to use low voltage non-volatile memory with today's low voltage microprocessors and peripherals in battery powered applications.

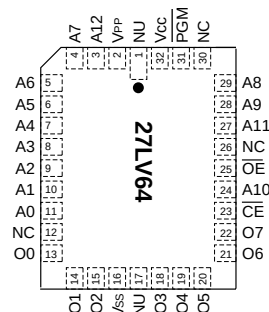
A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC or SOIC packaging is available. Tape and reel packaging is also available for PLCC or SOIC packages.

PACKAGE TYPES

DIP/SOIC



PLCC



1.0 ELECTRICAL CHARACTERISTICS

1.1 Maximum Ratings*

V_{CC} and input voltages w.r.t. V_{SS} -0.6V to + 7.25V

V_{PP} voltage w.r.t. V_{SS} during

programming -0.6V to +14V

Voltage on A9 w.r.t. V_{SS} -0.6V to +13.5V

Output voltage w.r.t. V_{SS} -0.6V to V_{CC} +1.0V

Storage temperature -65°C to +150°C

Ambient temp. with power applied -65°C to +125°C

*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0-A12	Address Inputs
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
$\overline{PGM}$	Program Enable
V _{PP}	Programming Voltage
O0 - O7	Data Output
V _{CC}	+5V Or +3V Power Supply
V _{SS}	Ground
NC	No Connection; No Internal Connections
NU	Not Used; No External Connection Is Allowed

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

V _{CC} = 3.0V to 5.5V unless otherwise specified Commercial: Tamb = 0°C to +70°C Industrial: Tamb = -40°C to +85°C							
Parameter	Part*	Status	Symbol	Min.	Max.	Units	Conditions
Input Voltages	all	Logic "1" Logic "0"	V _{IH} V _{IL}	2.0 -0.5	V _{CC} +1 0.8	V V	
Input Leakage	all	—	I _{LI}	-10	10	μA	V _{IN} = 0 to V _{CC}
Output Voltages	all	Logic "1" Logic "0"	V _{OH} V _{OL}	2.4	0.45	V V	I _{OH} = -400 μA I _{OL} = 2.1 mA
Output Leakage	all	—	I _{LO}	-10	10	μA	V _{OUT} = 0V to V _{CC}
Input Capacitance	all	—	C _{IN}	—	6	pF	V _{IN} = 0V; Tamb = 25°C; f = 1 MHz
Output Capacitance	all	—	C _{OUT}	—	12	pF	V _{OUT} = 0V; Tamb = 25°C; f = 1 MHz
Power Supply Current, Active	C I	TTL input TTL input	I _{CC1} I _{CC2}	— —	20 @ 5.0V 8 @ 3.0V 25 @ 5.0V 10 @ 3.0V	mA mA mA mA	V _{CC} = 5.5V; V _{PP} = V _{CC} f = 1 MHz; OE = CE = V _{IL} ; I _{OUT} = 0 mA; V _{IL} = -0.1 to 0.8V; V _{IH} = 2.0 to V _{CC} ; Note 1
Power Supply Current, Standby	C I all	TTL input TTL input CMOS input	I _{CC(S)}	—	1 @ 3.0V 2 @ 3.0V 100 @ 3.0V	mA mA μA	$\overline{CE}$ = V _{CC} ± 0.2V

* Parts: C=Commercial Temperature Range; I=Industrial Temperature Range

Note 1: Typical active current increases .5 mA per MHz up to operating frequency for all temperature ranges.

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

		AC Testing Waveform:		V _{IH} = 2.4V and V _{IL} = 0.45V; V _{OH} = 2.0V V _{OL} = 0.8V					
		Output Load:		1 TTL Load + 100 pF					
		Input Rise and Fall Times:		10 ns					
		Ambient Temperature:		Commercial:		Tamb = 0°C to +70°C			
				Industrial:		Tamb = -40°C to +85°C			
Parameter	Sym	27LV64-20		27LV64-25		27LV64-30		Units	Conditions
		Min.	Max.	Min.	Max.	Min.	Max.		
Address to Output Delay	t _{ACC}	—	200	—	250	—	300	ns	$\overline{CE} = \overline{OE} = V_{IL}$
$\overline{CE}$ to Output Delay	t _{CE}	—	200	—	250	—	300	ns	$\overline{OE} = V_{IL}$
$\overline{OE}$ to Output Delay	t _{OE}	—	100	—	125	—	125	ns	$\overline{CE} = V_{IL}$
$\overline{CE}$ or $\overline{OE}$ to O/P High Impedance	t _{OFF}	0	50	0	50	0	50	ns	
Output Hold from Address $\overline{CE}$ or $\overline{OE}$, whichever goes first	t _{OH}	0	—	0	—	0	—	ns	

FIGURE 1-1: READ WAVEFORMS

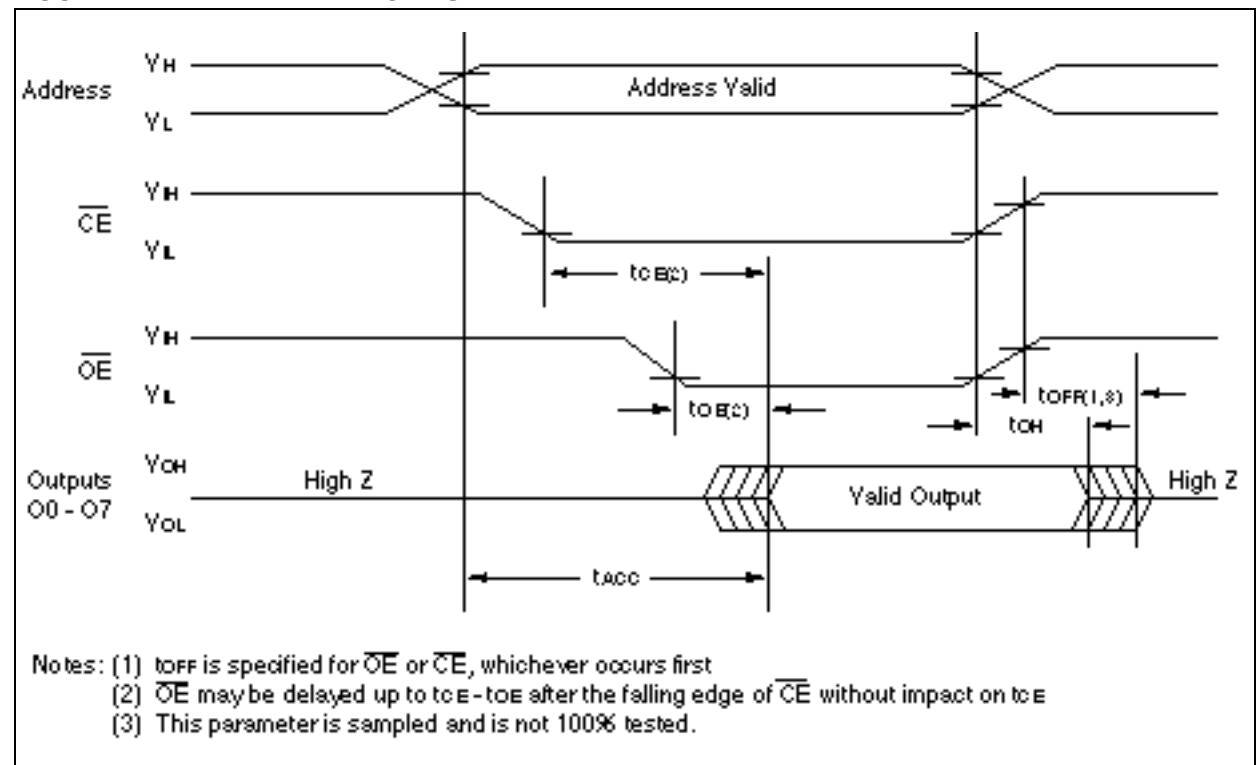


TABLE 1-4: PROGRAMMING DC CHARACTERISTICS

Ambient Temperature: Tamb = 25°C ± 5°C VCC = 6.5V ± 0.25V, VPP = VH = 13.0V ± 0.25V						
Parameter	Status	Symbol	Min.	Max.	Units	Conditions
Input Voltages	Logic"1" Logic"0"	VIH VIL	2.0 -0.1	VCC+1 0.8	V V	
Input Leakage	—	ILI	-10	10	μA	VIN = 0V to VCC
Output Voltages	Logic"1" Logic"0"	VOH VOL	2.4	0.45	V V	IOH = -400 μA IOL = 2.1 mA
VCC Current, program & verify	—	ICC2	—	20	mA	Note 1
VPP Current, program	—	I PP2	—	25	mA	Note 1
A9 Product Identification	—	VH	11.5	12.5	V	

Note 1: VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP.

TABLE 1-5: PROGRAMMING AC CHARACTERISTICS

for Program, Program Verify and Program Inhibit Modes	AC Testing Waveform: $V_{IH}=2.4V$ and $V_{IL}=0.45V$; $V_{OH}=2.0V$; $V_{OL}=0.8V$ Ambient Temperature: $T_{amb}=25^{\circ}C \pm 5^{\circ}C$ $V_{CC}= 6.5V \pm 0.25V$, $V_{PP} = V_H = 13.0V \pm 0.25V$				
Parameter	Symbol	Min.	Max.	Units	Remarks
Address Set-Up Time	tAS	2	—	μs	
Data Set-Up Time	tDS	2	—	μs	
Data Hold Time	tDH	2	—	μs	
Address Hold Time	tAH	0	—	μs	
Float Delay (2)	tDF	0	130	ns	
VCC Set-Up Time	tVCS	2	—	μs	
Program Pulse Width (1)	tpW	95	105	μs	100 μs typical
$\overline{CE}$ Set-Up Time	tCES	2	—	μs	
$\overline{OE}$ Set-Up Time	tOES	2	—	μs	
VPP Set-Up Time	tVPS	2	—	μs	
Data Valid from $\overline{OE}$	tOE		100	ns	

Note 1: For express algorithm, initial programming width tolerance is 100 μs ±5%.

Note 2: This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).

FIGURE 1-2: PROGRAMMING WAVEFORMS (1)

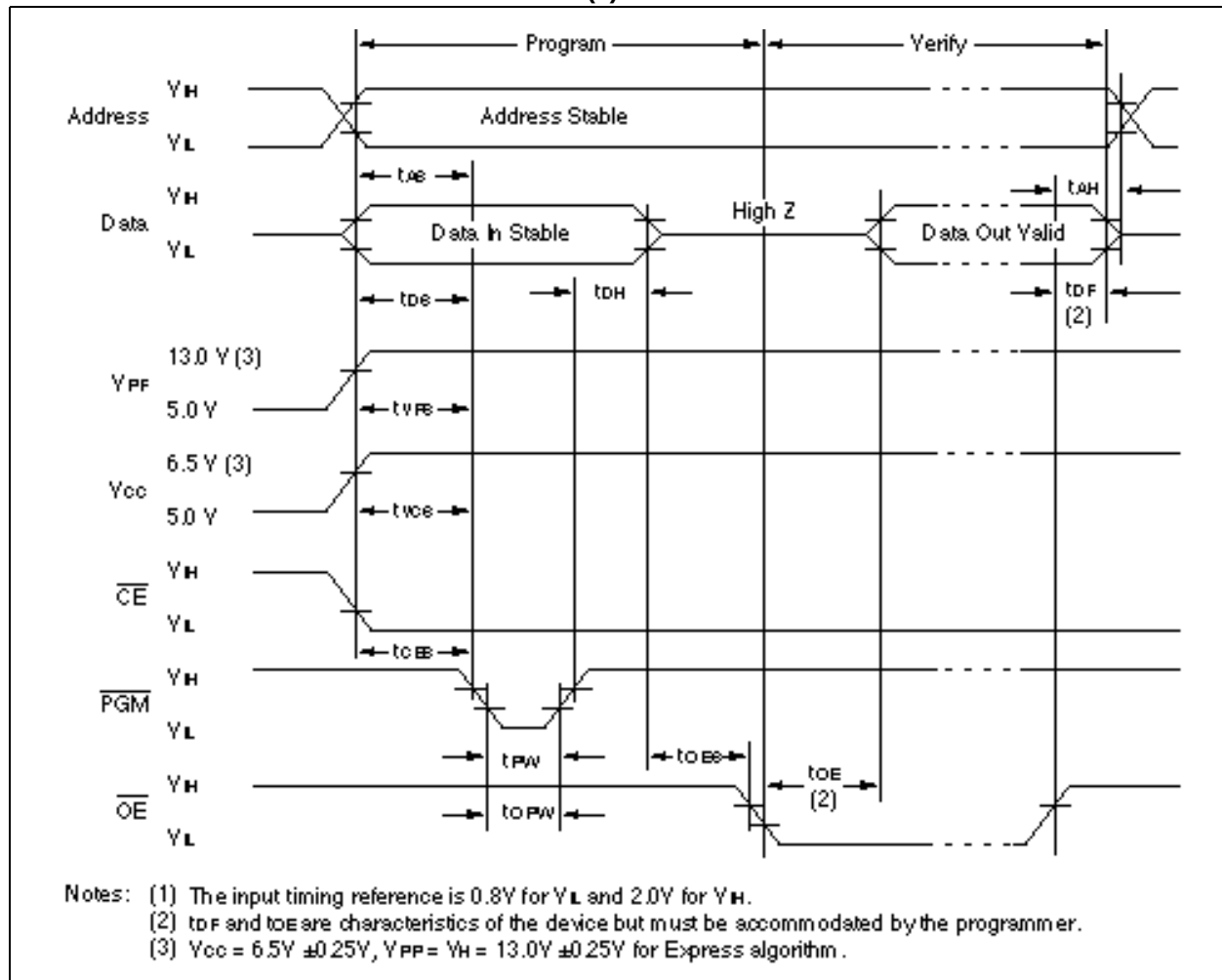


TABLE 1-6: MODES

Operation Mode	$\overline{CE}$	$\overline{OE}$	$\overline{PGM}$	V_{PP}	A9	O0 - O7
Read	V_{IL}	V_{IL}	V_{IH}	V_{CC}	X	DOUT
Program	V_{IL}	V_{IH}	V_{IL}	V_H	X	DIN
Program Verify	V_{IL}	V_{IL}	V_{IH}	V_H	X	DOUT
Program Inhibit	V_{IH}	X	X	V_H	X	High Z
Standby	V_{IH}	X	X	V_{CC}	X	High Z
Output Disable	V_{IL}	V_{IH}	V_{IH}	V_{CC}	X	High Z
Identity	V_{IL}	V_{IL}	V_{IH}	V_{CC}	V_H	Identity Code

X = Don't Care

1.2 Read Mode

(See Timing Diagrams and AC Characteristics)

Read Mode is accessed when

- the $\overline{CE}$ pin is low to power up (enable) the chip
- the $\overline{OE}$ pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time (t_{ACC}) is equal to the delay from $\overline{CE}$ to output (t_{CE}). Data is transferred to the output after a delay from the falling edge of $\overline{OE}$ (t_{OE}).

1.3 Standby Mode

The standby mode is defined when the $\overline{CE}$ pin is high (V_{IH}) and a program mode is not defined.

When these conditions are met, the supply current will drop from 20 mA to 100 μ A.

1.4 Output Enable

This feature eliminates bus contention in microprocessor-based systems in which multiple devices may drive the bus. The outputs go into a high impedance state when the following condition is true:

- The $\overline{OE}$ and $\overline{PGM}$ pins are both high.

1.5 Erase Mode (U.V. Windowed Versions)

Windowed products offer the capability to erase the memory array. The memory matrix is erased to the all 1's state when exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm² is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of 12,000 μ W/cm² for approximately 20 minutes.

1.6 Programming Mode

The Express Algorithm has been developed to improve the programming throughput times in a production environment. Up to ten 100-microsecond pulses are applied until the byte is verified. No overprogramming is required. A flowchart of the express algorithm is shown in Figure 1-3.

Programming takes place when:

- V_{CC} is brought to the proper voltage,
- V_{PP} is brought to the proper V_H level,
- the $\overline{CE}$ pin is low,
- the $\overline{OE}$ pin is high, and
- the $\overline{PGM}$ pin is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0-A12 and the data to be programmed is presented to pins O0-O7. When data and address are stable, $\overline{OE}$ is high, $\overline{CE}$ is low and a low-going pulse on the $\overline{PGM}$ line programs that location.

1.7 Verify

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- V_{CC} is at the proper level,
- V_{PP} is at the proper V_H level,
- the $\overline{CE}$ line is low,
- the $\overline{PGM}$ line is high, and
- the $\overline{OE}$ line is low.

1.8 Inhibit

When programming multiple devices in parallel with different data, only $\overline{CE}$ or $\overline{PGM}$ need be under separate control to each device. By pulsing the $\overline{CE}$ or $\overline{PGM}$ line low on a particular device in conjunction with the $\overline{PGM}$ or $\overline{CE}$ line low, that device will be programmed; all other devices with $\overline{CE}$ or $\overline{PGM}$ held high will not be programmed with the data, although address and data will be available on their input pins (i.e., when a high level is present on $\overline{CE}$ or $\overline{PGM}$); and the device is inhibited from programming.

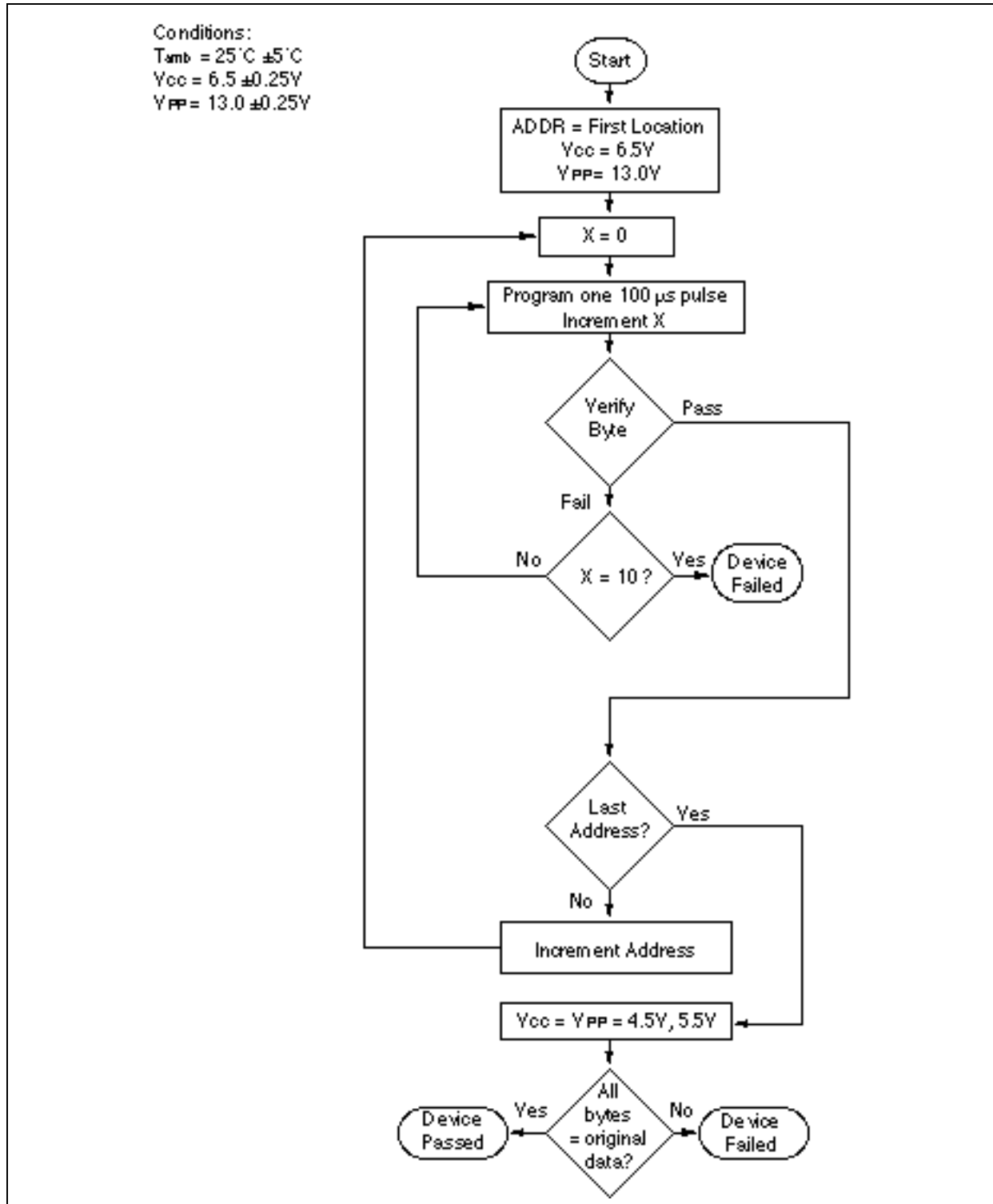
1.9 Identity Mode

In this mode specific data is output which identifies the manufacturer as Microchip Technology Inc. and device type. This mode is entered when Pin A9 is taken to V_H (11.5V to 12.5V). The $\overline{CE}$ and $\overline{OE}$ lines must be at V_{IL}. A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin $\rightarrow$	Input	Output								
Identity $\downarrow$	A0	0 7	0 6	0 5	0 4	0 3	0 2	0 1	0 0	H e x
Manufacturer	V _{IL}	0	0	1	0	1	0	0	1	29
Device Type*	V _{IH}	0	0	0	0	0	0	1	0	02

* Code subject to change

FIGURE 1-3: PROGRAMMING EXPRESS ALGORITHM



27LV64 Product Identification System

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.

27LV64	-	25	I	/P	
					Package:
					L = Plastic Leaded Chip Carrier
					P = Plastic DIP (600 Mil)
					SO = Plastic SOIC (300 Mil)
					Temperature Range:
					Blank = 0°C to +70°C
					I = -40°C to +85°C
					Access Time:
					20 = 200 ns
					25 = 250 ns
					30 = 300 ns
					Device:
					27LV64 64K (8K x 8) Low-Voltage CMOS EPROM

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

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Microchip received ISO/TS-16949:2002 quality system certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona and Mountain View, California in October 2003. The Company's quality system processes and procedures are for its PICmicro® 8-bit MCUs, KEELoQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



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